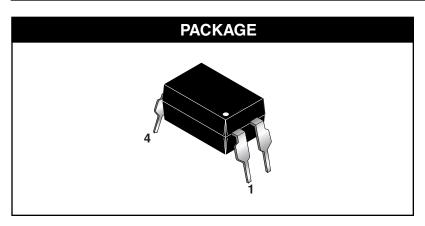
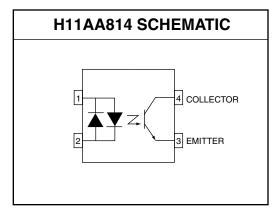


H11AA814 SERIES

H11A817 SERIES





DESCRIPTION

The H11AA814 Series consists of two gallium arsenide infrared emitting diodes, connected in inverse parallel, driving a single silicon phototransistor in a 4-pin dual in-line package.

The H11A817 Series consists of a gallium arsenide infrared emitting diode driving a silicon phototransistor in a 4-pin dual in-line package.

FEATURES

- · Compact 4-pin package
- Current transfer ratio in selected groups:

H11AA814: 20-300% H11A817: 50-600% H11AA814A: 50-150% H11A817A: 80-160% H11A817B: 130-260% H11A817C: 200-400%

H11A817C: 200-400% H11A817D: 300-600%

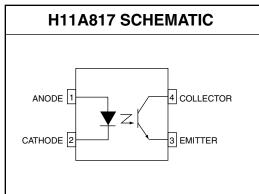
APPLICATIONS

H11AA814 Series

- AC line monitor
- Unknown polarity DC sensor
- Telephone line interface

H11A817 Series

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs





H11AA814 SERIES

H11A817 SERIES

Parameter	Symbol	Device	Value	Units
TOTAL DEVICE				
Storage Temperature	T _{STG}	All	-55 to +150	°C
Operating Temperature	T _{OPR}	All	-55 to +100	°C
Lead Solder Temperature	T _{SOL}	All	260 for 10 sec	°C
Total Device Power Dissipation (-55°C to 50 °C)	P _D	All	200	mW
EMITTER				
Continuous Forward Current	I _F	All	50	mA
Reverse Voltage	V _R	H11A817, H11A817A, H11A817B, H11A817C, H11A817C, H11A817D	5	V
Forward Current - Peak (1 µs pulse, 300 pps)	I _F (pk)	All	1.0	Α
LED Power Dissipation (25°C ambient) Derate above 25°C	P _D	All 100 1.33		mW mW/°C
DETECTOR				
Collector-Emitter Voltage	V _{CEO}	All	35	V
Emitter-Collector Voltage	V _{ECO}	All 6		V
Continuous Collector Current	I _C	All 50		mA
Detector Power Dissipation (25°C ambient)		All	150	mW
Derate above 25°C	rate above 25°C		2.0	mW/°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C Unless otherwise specified.)

INDIVIDUAL COMPONENT CHARACTERISTICS

Parameter	Test Conditions	Symbol	Device	Min	Тур	Max	Unit
EMITTER	(I _F = 20 mA)	V _F	H11A817, H11A17A, H11A817B, H11A817C, H11A817D		1.2	1.5	V
Input Forward Voltage	put Forward Voltage $(I_F = \pm 20 \text{ mA})$		H11AA814		1.2	1.5	1
			H11A817, H11A17A,				
Reverse Leakage Current	$(V_{R} = 5.0 V)$	I _R	H11A817B, H11A817C,		.001	10	μΑ
			H11A817D				
DETECTOR							
Collector-Emitter Breakdown Voltage	$(I_C = 1.0 \text{ mA}, I_F = 0)$	BV _{CEO}	ALL	35	100		V
Emitter-Collector Breakdown Voltage	$(I_E = 100 \mu A, I_F = 0)$	BV _{ECO}	ALL	6	10		٧
Collector-Emitter Dark Current	$(V_{CE} = 10V, I_F = 0)$	I _{CEO}	ALL		.025	100	nA
Collector-Emitter Capacitance (V _{CE} = 0 V, f = 1 MHz)		C _{CE}	ALL		8		pF



H11AA814 SERIES

H11A817 SERIES

TRANSFER CHARACTERISTICS (T _A = 25°C Unless otherwise specified.)							
DC Characteristic	Test Conditions	Symbol	Device	Min	Тур	Max	Unit
	$(I_F = \pm 1 \text{ mA}, V_{CE} = 5 \text{ V}) \text{ (note 1)}$	CTR	H11AA814	20		300	%
	$(I_F = \pm 1 \text{ mA}, V_{CE} = 5 \text{ V}) \text{ (note 1)}$	CTR	H11AA814A	50		150	%
Current Transfer Ratio	(I _F = 5 mA, V _{CE} = 5 V) (note 1)	CTR	H11A817	50		600	%
			H11A817A	80		160	%
			H11A817B	130		260	%
			H11A817C	200		400	%
			H11A817D	300		600	%
Collector-Emitter Saturation Voltage	$(I_C = 1 \text{ mA}, I_F = \pm 20 \text{ mA})$	V _{CE (SAT)}	ALL		.1	.2	٧
AC Characteristic							
Rise Time	$(I_C = 2 \text{ mA}, V_{CE} = 2 \text{ V}, R_L = 100 \text{V}) \text{ (note 1)}$	T _R	ALL		2.4	18	μs
Fall Time	$(I_C = 2 \text{ mA}, V_{CE} = 2 \text{ V}, R_L = 100 \text{V}) \text{ (note 1)}$	T _F	ALL		2.4	18	μs

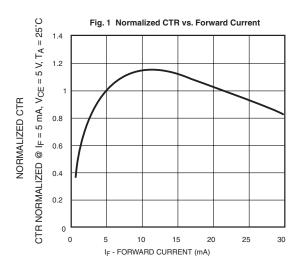
ISOLATION CHARACTERISTICS						
Characteristic	Test Conditions	Symbol	Min	Тур	Max	Units
Input-Output Isolation Voltage (note 3)	(I _{I-O} [1 μA, 1 min.)	V _{ISO}	5300			Vac(rms)
Isolation Resistance	(V _{I-O} = 500 VDC)	R _{ISO}	10 ¹¹			Ω
Isolation Capacitance	(V _{I-O} = &, f = 1 MHz)	C _{ISO}		0.5		pf

NOTES

- 1. Current Transfer Ratio (CTR) = $I_C/I_F \times 100\%$.
- 2. For test circuit setup and waveforms, refer to Figure 8.
- 3. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.

H11AA814 SERIES

H11A817 SERIES



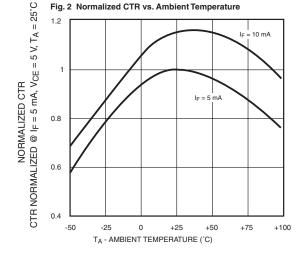
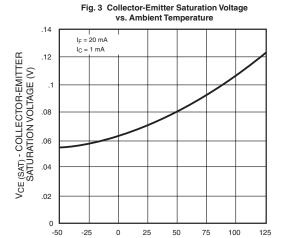
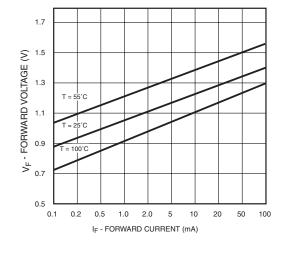


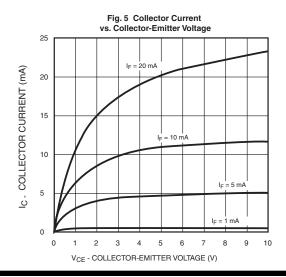
Fig. 2 Normalized CTR vs. Ambient Temperature



T_A - AMBIENT TEMPERATURE (°C)



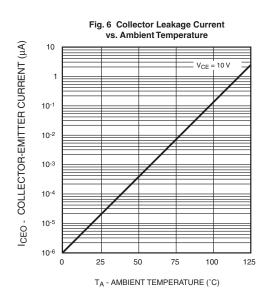






H11AA814 SERIES

H11A817 SERIES



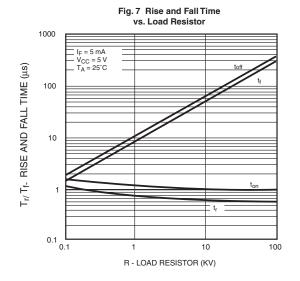
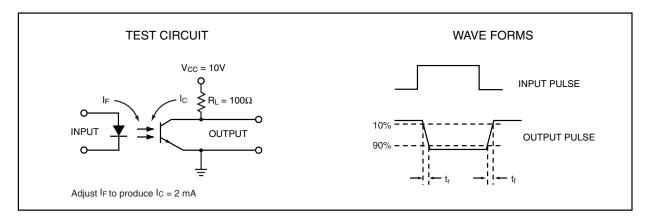
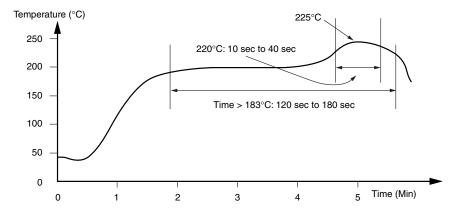


Figure 8. Switching Time Test Circuit and Waveforms



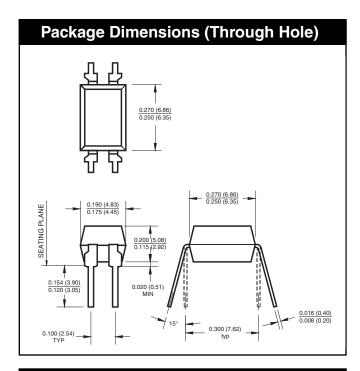
Recommended Thermal Reflow Profile for Surface Mount DIP Package

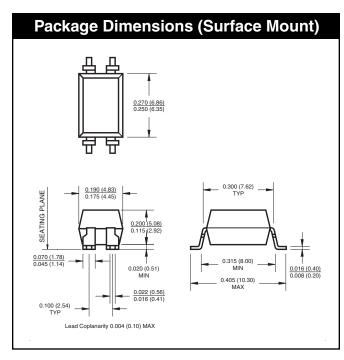




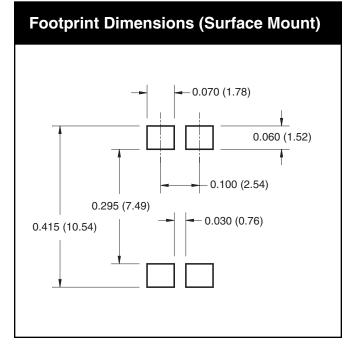
H11AA814 SERIES

H11A817 SERIES





Package Dimensions (0.4" Lead Spacing) 0.190 (4.83) 0.190 (4.85) 0.175 (4.45) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54) 0.100 (2.54)



NOTEAll dimensions are in inches (millimeters)

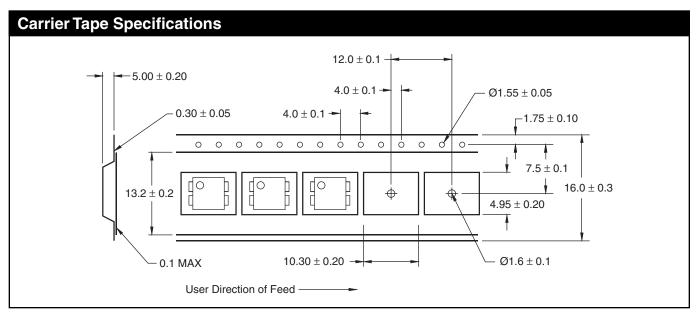


H11AA814 SERIES

H11A817 SERIES

ORDERING INFORMATION

Option	Order Entry Identifier	Description
S	.S	Surface Mount Lead Bend
SD	.SD	Surface Mount; Tape and reel
W	.W	0.4" Lead Spacing
300	.300	VDE 0884
300W	.300W	VDE 0884, 0.4" Lead Spacing
3S	.3S	VDE 0884, Surface Mount
3SD	.3SD	VDE 0884, Surface Mount, Tape & Reel



NOTEAll dimensions are in millimeters



H11AA814 SERIES

H11A817 SERIES

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